묽은 자성반도체 Cd_{1-x-y}Mn_xHg_yTe 단결정의 Faraday 회전 황영훈^{*}, 김혜경, 엄영호

왕당군, 김에경, 담당모 울산대학교 물리학과, 울산, 680-749 박효열 울산과학대학 반도체응용과, 울산, 680-749 진광수

부산대학교 물리학과, 부산, 609-735 (Faraday Rotation of Diluted Magnetic Semiconductors Cd_{1-x-y}Mn_xHg_yTe Single Crystals)

Younghun Hwang*, HyeKyeong Kim, and YoungHo Um
Department of Physics, University of Ulsan, Ulsan 680-749, South Korea
Hyoyeol Park
Department of Semiconductors Applications, Ulsan College, Ulsan 680-749, South Korea
Gwangsoo Jeen

Department of Physics, Pusan Nat'l Univ., Pusan 609-735, South Korea

Abstract $Cd_{1-x-y}Mn_xHg_yTe$ single crystals were grown by using the vertical Bridgman method. The Verdet constant was evaluated as a function of the photon energy by using the result for the Faraday rotation. The Verdet curve was well fitted by using a single-oscillator method and shifted downward at $y \ge 0$ due to the exchange interaction. The Faraday rotation decreased linearly with increasing magnetic field from 0 KG to 8KG.

- 1. Introduction The large magneto-optical effects in diluted magnetic semiconductors (DMSs) have been of great interest for many years[1]. DMSs are compounds based on typical semiconductors (CdTe and ZnSe), for which a fraction of nonmagnetic cations has been replaced by magnetic ions (Mn, Fe, Co, and Cr). Among these properties, the strong spin-spin exchange interaction occurring between the d electrons of the Mn^{2+} ions and s-like conduction-band and p-like valence-band electrons profoundly affects all physical phenomena that depend on the Zeeman splitting of the band sublevels. For instance, this spin-spin exchange interaction leads to the well-known gaint Faraday rotation observed at photon energies E near the band-gap resonance[2,3]. The effect has been subsequently studied in various DMSs, in particular, in the optically isotropic CdMnTe and ZnMnTe[4]. In this paper, we investigate the Faraday rotation study on the quaternary CdMnHgTe crystals as a function of Hg compositions and magnetic field.
- 2. Experimental Procedure The $Cd_{1-x-y}Mn_xHg_yTe$ single crystals were grown by using the vertical Bridgman method. The mole fraction x and y was determined by Electron Probe Microanalyzer (EPMA-1400, SHIMADZU) and X-ray diffraction (XRD) measurements. Faraday rotation was measured by placing the sample in a magnetic field of an electromagnet and between two polaroid sheets set at 45° with respect to each other. Using this apparatus, rotation as small as 0.1° could be easily determined.
- 3. Results and Discussion Figure 1 shows the change in lattice constant with Hg concentration. This quaternary system crystallizes in the zinc-blende structure in the composition range y=0.5, and also it is found that the lattice constant decrease with Hg concentration. Figure 2 shows the Verdet constants in $Cd_{1-x-y}Mn_xHg_yTe$ (y=0, 0.01, 0.03, and 0.05) at room temperature plotted as a function of the photon energy in the resonant part of the spectra with an expanded scale (1.2–2.1 eV). Figure 3 shows the magnetic field dependence of the Faraday rotation with increasing magnetic field at λ

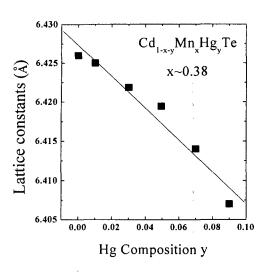


Fig. 1. Lattice constants as a function of Hg mole fraction y

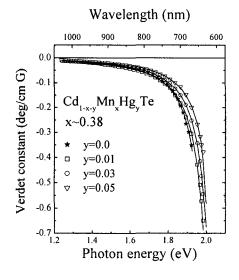
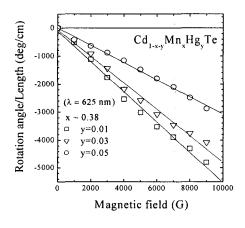


Fig. 2. Verdet constant for CdMnHgTe at R.T. for Hg mole fraction y. Solid line is the fit by single-oscillator model.



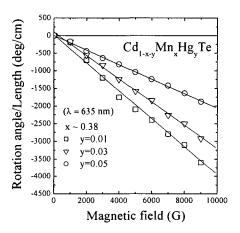


Fig. 3. Magnetic field dependence of the Faraday rotation with increasing magnetic field. The solid line represents a least-squares fit.

4. Summary $Cd_{1-x-y}Mn_xHg_yTe$ single crystals were grown by using the vertical Bridgman method. The Verdet constant was evaluated as a function of the photon energy by using the result for the Faraday rotation. The Verdet curve was well fitted by using a single-oscillator method and shifted downward at $y \ge 0$ due to the exchange interaction. The Faraday rotation decreased linearly with increasing magnetic field from 0 KG to 8KG.

5. References

- [1] J. K. Furdyna et al., Semiconductor and Semimetals Academic, Vol. 25, (1988).
- [2] A. V. Komarov, S. M. Ryabchenko, O. V. Terletskii, I. I. Zheru, and R. D. Ivanchuk, Sov. Phys. JEPT 46, 318 (1977).
- [3] J. A. Gaj, R. R. Galazka, and M. Nawrocki, Solid State Commun. 25, 193 (1978).
- [4] D. U. Bartholomew, J. K. Furdyna, and A. K. Ramdas, Phys. Rev. B 34, 6943 (1986).